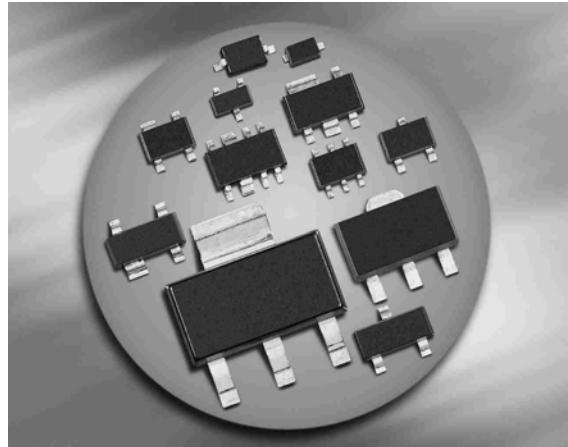


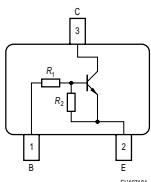
NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=22\text{k}\Omega$, $R_2=47\text{k}\Omega$)



BCR142/F/L3

BCR142T/W



Type	Marking	Pin Configuration						Package
BCR142	WZs	1=B	2=E	3=C	-	-	-	SOT23
BCR142F	WZs	1=B	2=E	3=C	-	-	-	TSFP-3
BCR142FL3	WZ	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR142T	WZs	1=B	2=E	3=C	-	-	-	SC75
BCR142W	WZs	1=B	2=E	3=C	-	-	-	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Emitter-base voltage	V_{EBO}	10	
Input on voltage	$V_{i(on)}$	30	
Collector current	I_C	100	mA
Total power dissipation- BCR142, $T_S \leq 102^\circ\text{C}$	P_{tot}	200	mW
BCR142F, $T_S \leq 128^\circ\text{C}$		250	
BCR142L3, $T_S \leq 135^\circ\text{C}$		250	
BCR142T, $T_S \leq 109^\circ\text{C}$		250	
BCR142W, $T_S \leq 124^\circ\text{C}$		250	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾ BCR142	R_{thJS}	≤ 240	K/W
BCR142F			
BCR142L3			
BCR142T			
BCR142W			

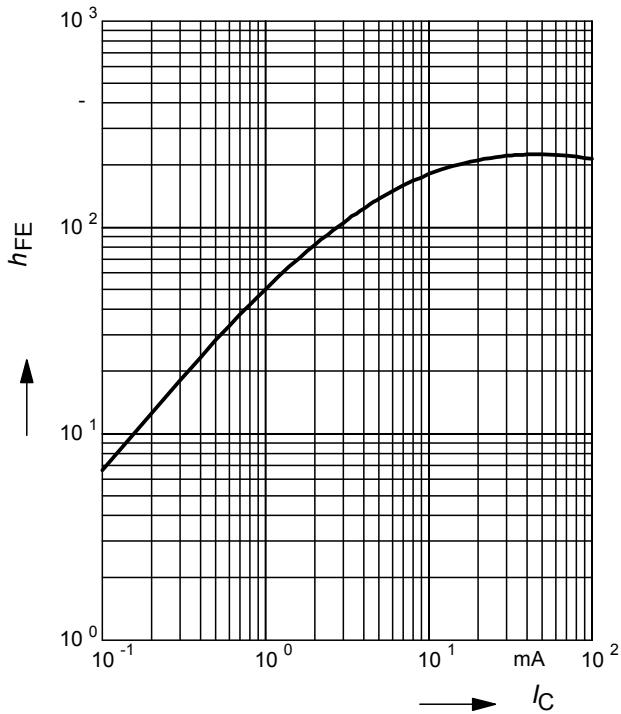
¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

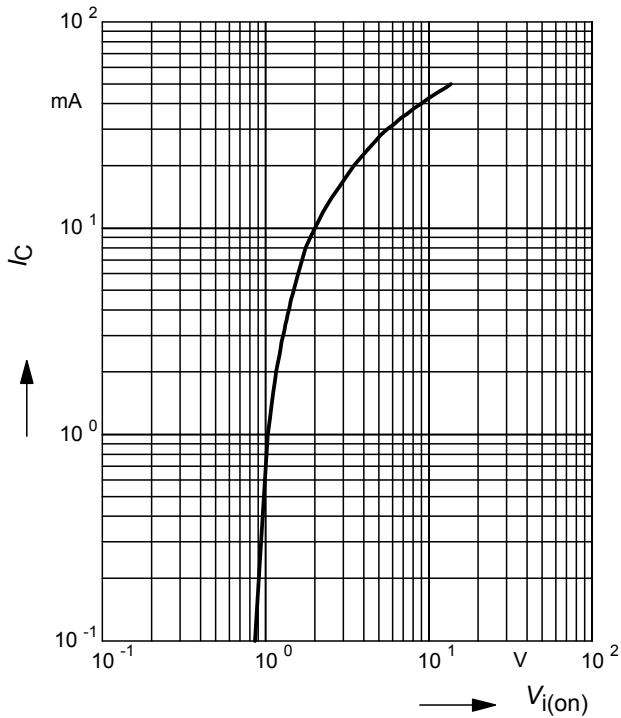
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(\text{BR})\text{CEO}}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(\text{BR})\text{CBO}}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$	I_{EBO}	-	-	227	μA
DC current gain ¹⁾ $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	h_{FE}	70	-	-	-
Collector-emitter saturation voltage ¹⁾ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(\text{off})}$	0.5	-	1.2	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$	$V_{i(\text{on})}$	0.8	-	2.5	
Input resistor	R_1	15	22	29	k Ω
Resistor ratio	R_1/R_2	0.42	0.47	0.52	-
AC Characteristics					
Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	f_T	-	150	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{cb}	-	3	-	pF

¹Pulse test: $t < 300\mu\text{s}$; $D < 2\%$

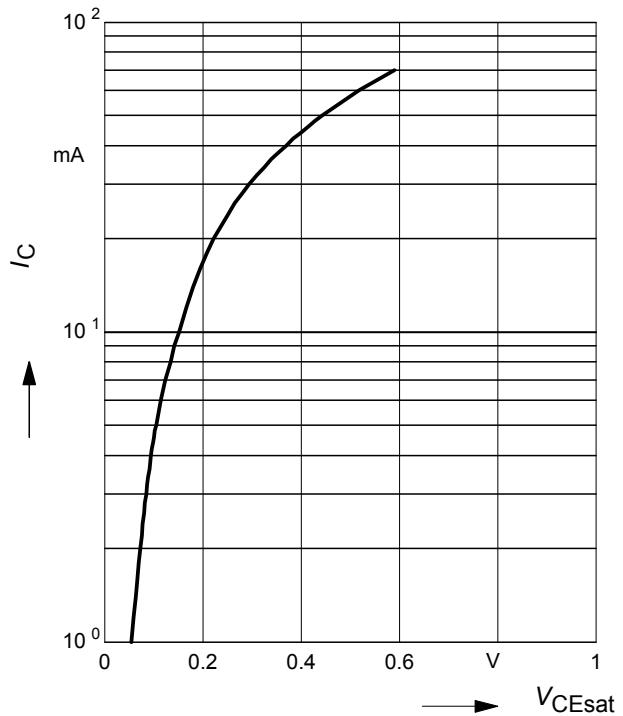
DC current gain $h_{FE} = f(I_C)$
 $V_{CE} = 5V$ (common emitter configuration)



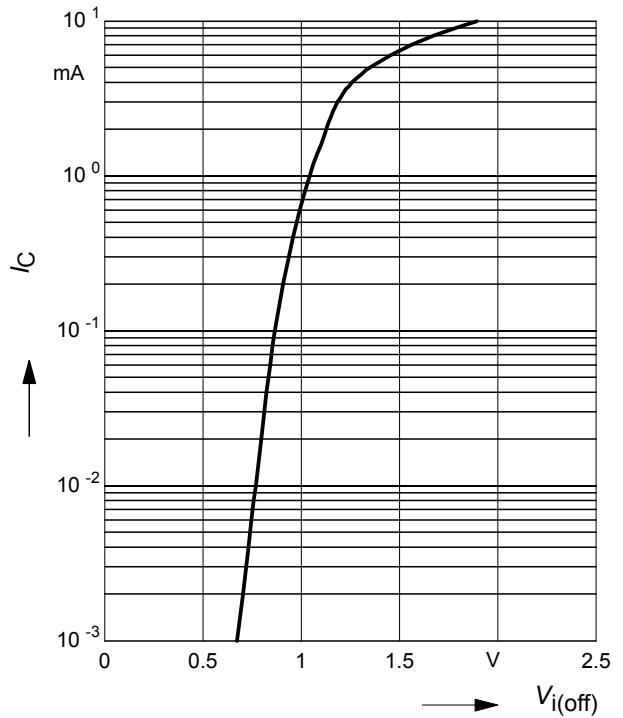
Input on Voltage $V_{i(on)} = f(I_C)$
 $V_{CE} = 0.3V$ (common emitter configuration)



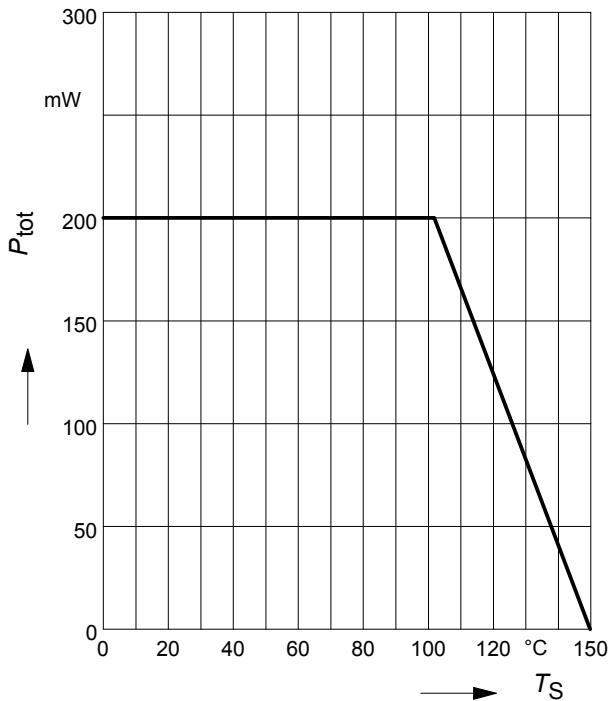
Collector-emitter saturation voltage
 $V_{CEsat} = f(I_C)$, $h_{FE} = 20$



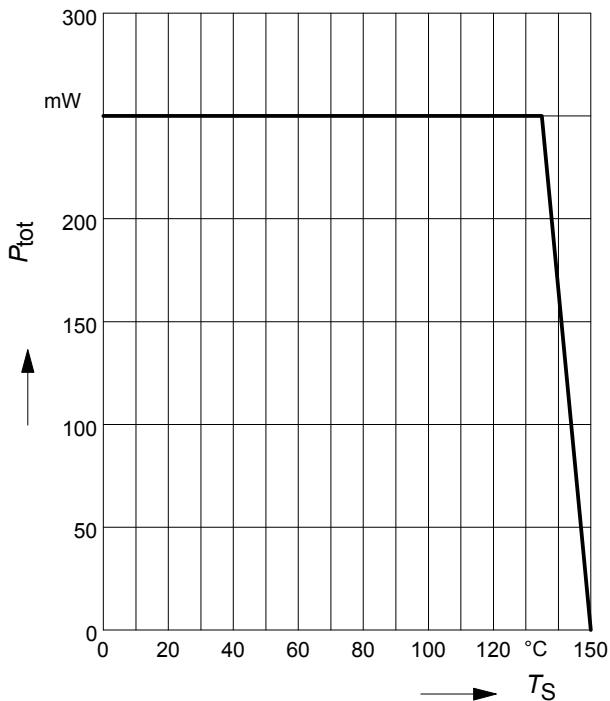
Input off voltage $V_{i(off)} = f(I_C)$
 $V_{CE} = 5V$ (common emitter configuration)



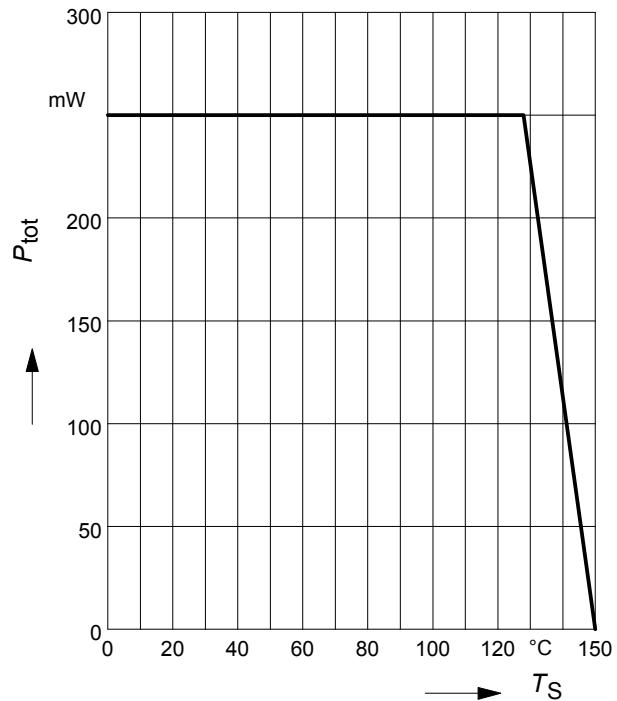
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR142



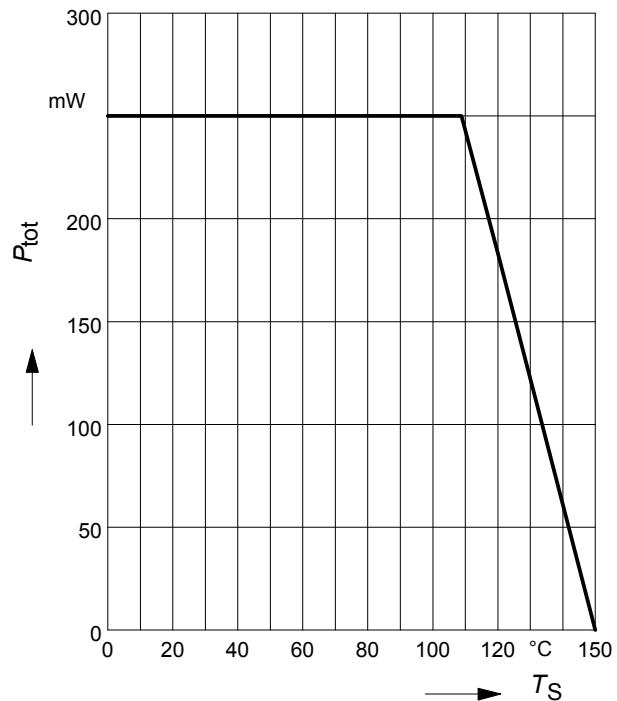
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR142L3



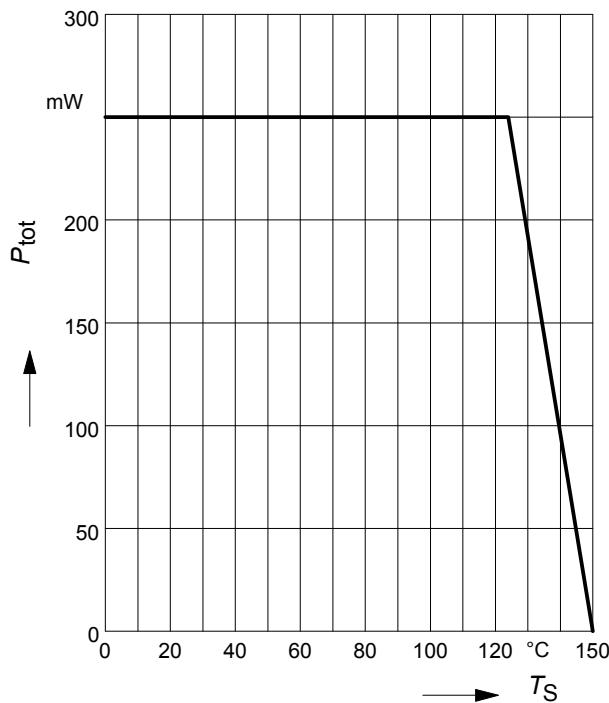
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR142F



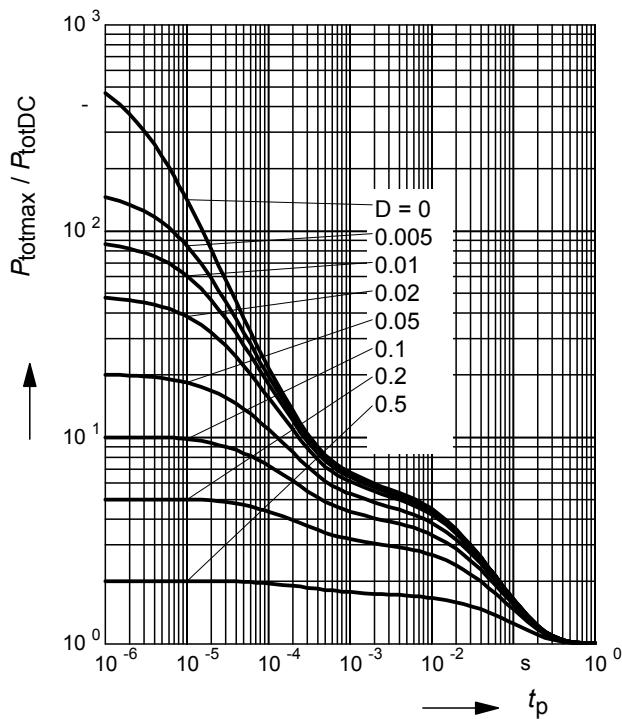
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR142T



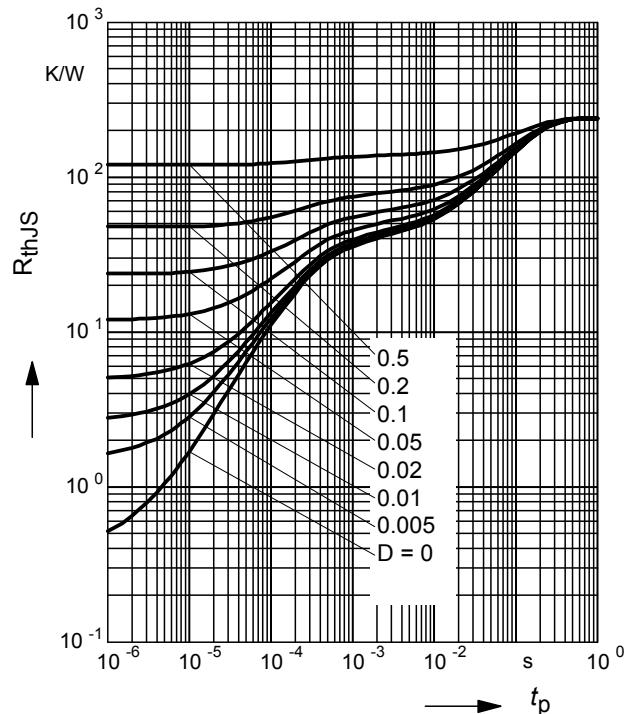
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR142W



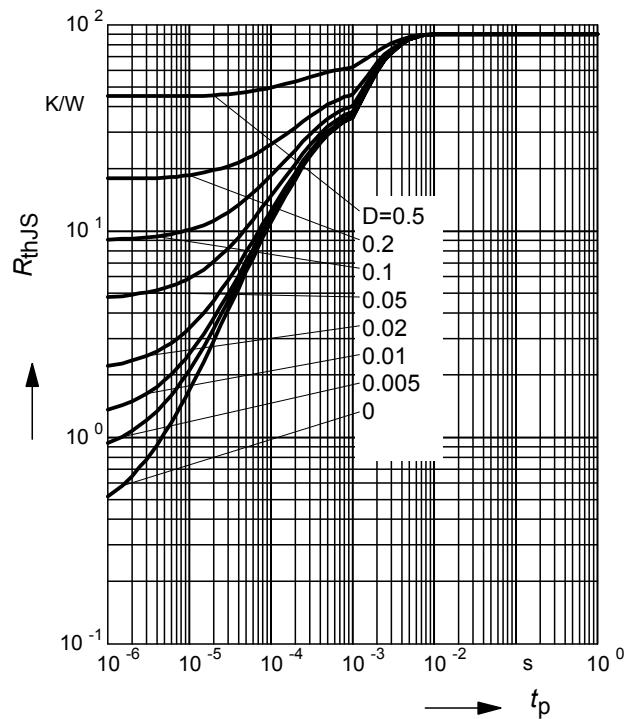
Permissible Pulse Load
 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$
BCR142



Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$
BCR142



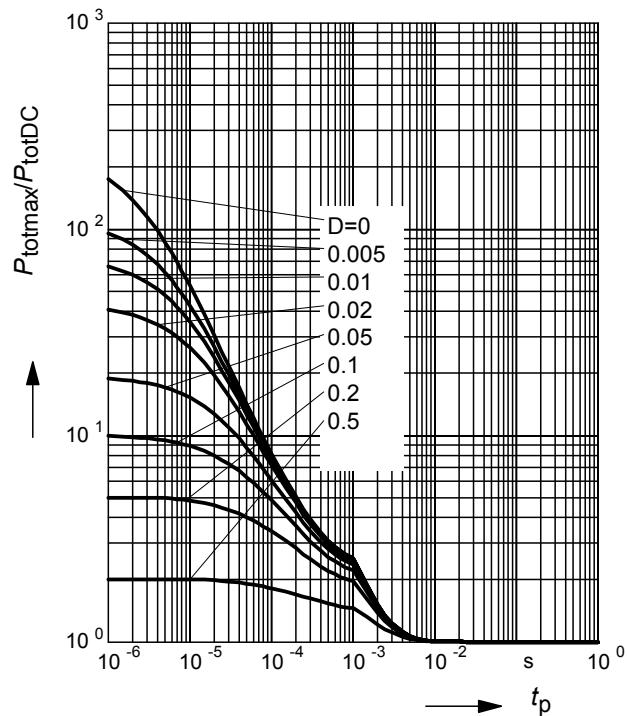
Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$
BCR142F



Permissible Pulse Load

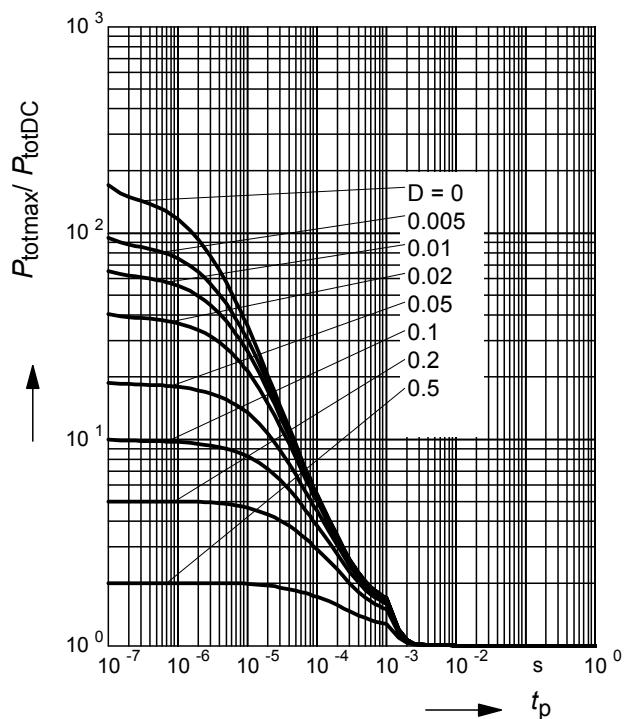
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR142F

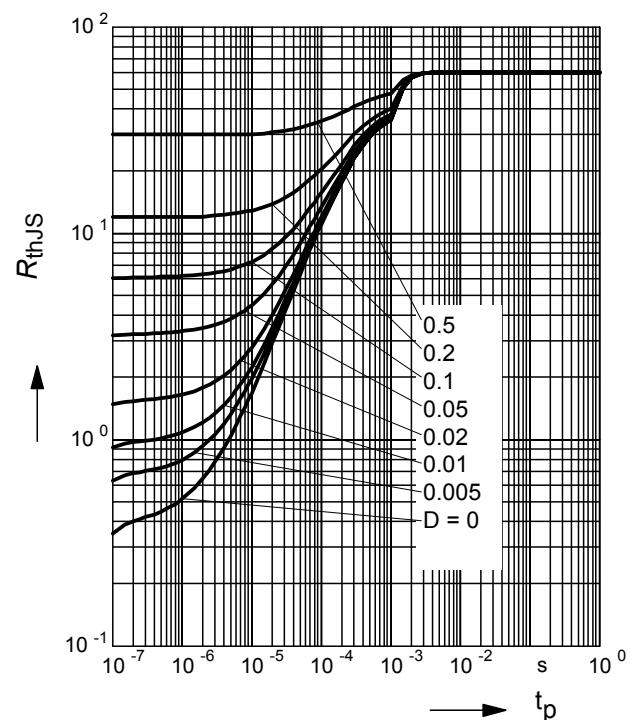

Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

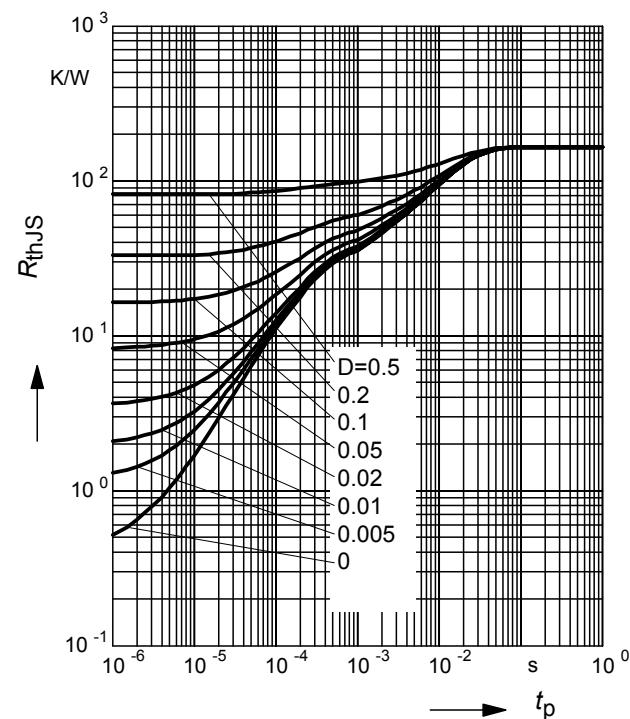
BCR142L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

BCR142L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

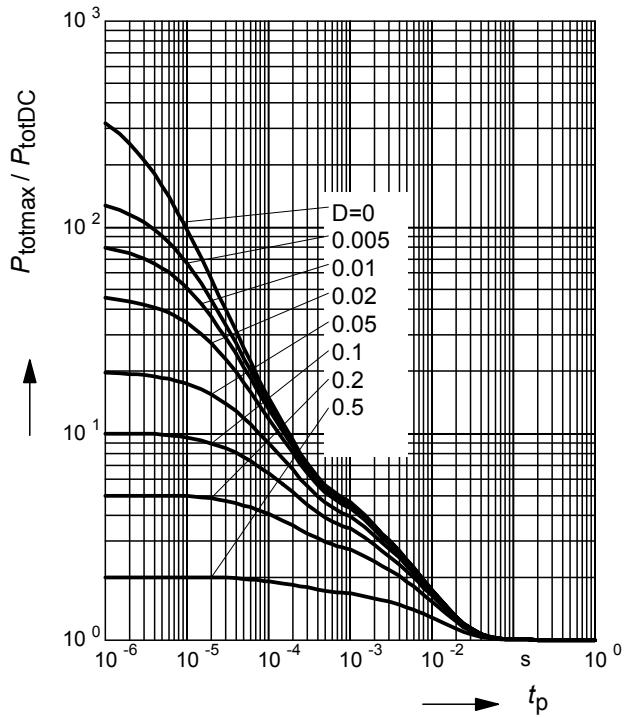
BCR142T



Permissible Pulse Load

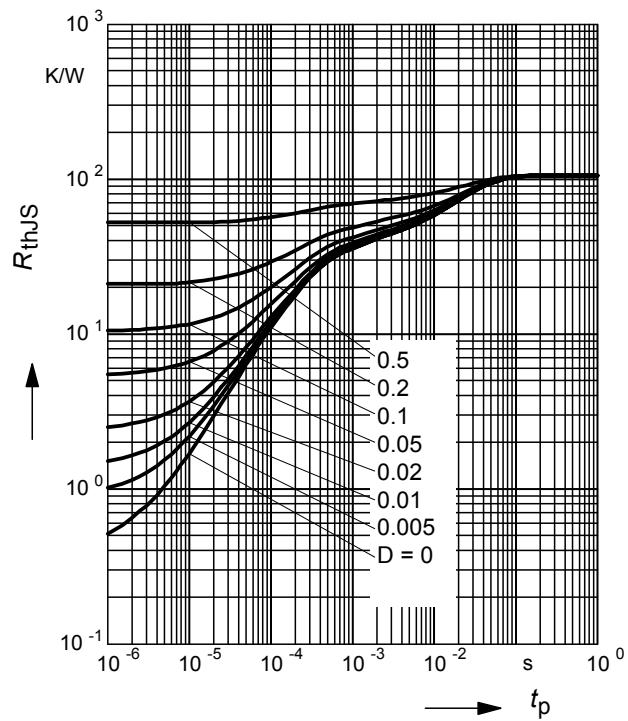
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR142T



Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$

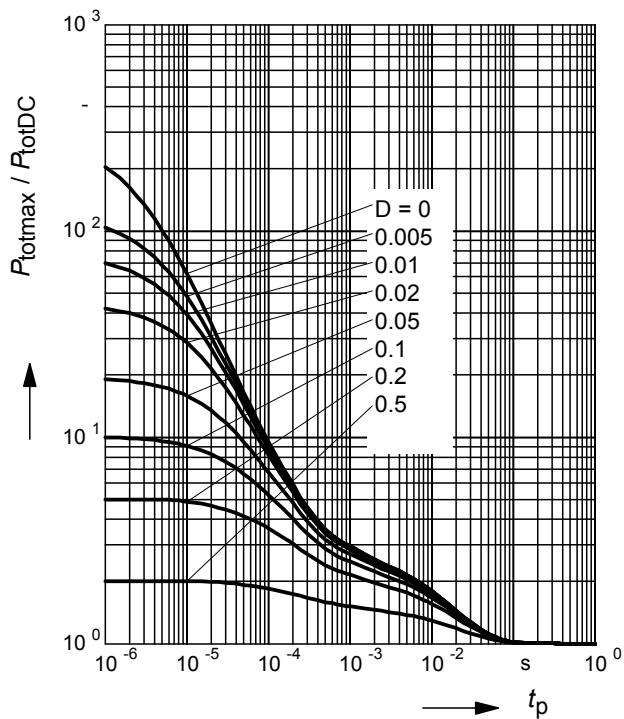
BCR142W



Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR142W



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